

# 90 W, 12.75 - 13.25 GHz, GaN MMIC, Power Amplifier

#### Description

The CMPA1C1D080F is a packaged, 90 W HPA utilizing the high performance, 0.25 um GaN on SiC production process. With a 12.75 - 13.25 GHz operating frequency range targeting satellite communications, the CMPA1C1D080F offers 3rd-order intermodulation performance of -30 dBc at 20 W of total output power. For exceptional thermal management, the HPA is offered in a bolt-down, flange package.



Package Types: 440222 PN's: CMPA1C1D080F

#### Features

- 90 W typical  $P_{sat}$ .
- >21% typical power added efficiency
- 25 dB small signal gain
- . 20 W total output power at -30 dBc IM3
- Operation up to 40 V

#### Note:

Features are typical performance across frequency under 25 °C operation. Please reference performance charts for additional details.



**Applications** 

Satellite communications uplink



## Typical Performance Over 12.75 - 13.25 GHz ( $T_c = 25 \text{ °C}$ )

Demonstern		12.0.011-		11-11-
Parameter	12.75 GHz	13.0 GHz	13.25 GHZ	Units
Small Signal Gain <sup>1,2</sup>	26.6	25.3	25.2	dB
Output Power <sup>1,3</sup>	49.7	49.9	49.7	dBm
Power Gain <sup>1,3</sup>	16.7	16.9	16.7	dB
Power Added Efficiency <sup>1,3</sup>	23	23	21	%
IM3 <sup>1,4</sup>	-27	-27	-27	dBc

Notes:

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 ${}^{1}V_{DD} = 40 \text{ V}, \text{ I}_{DQ} = 750 \text{ mA.}$  ${}^{2}\text{ Measured at P}_{\text{IN}} = -15 \text{ dBm.}$ 

<sup>3</sup> Measured at  $P_{IN}^{IN}$  = 33 dBm, CW.

<sup>4</sup>Measured at 40 dBm P<sub>out</sub>/Tone, 10 MHz.





## Absolute Maximum Ratings (Not Simultaneous) at 25 °C

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V <sub>DSS</sub>	120	V <sub>DC</sub>	25 °C
Gate-Source Voltage	V <sub>gs</sub>	-10, +2	V <sub>DC</sub>	25 °C
Storage Temperature	T <sub>stg</sub>	-55, +150	°C	
Maximum Forward Gate Current	Ι <sub>G</sub>	27	mA	25 °C
Maximum Drain Current	I <sub>DMAX</sub>	13.5	А	
Soldering Temperature	Ts	260	°C	
Junction Temperature	T,	225	°C	MTTF > 1e6 Hours

# Electrical Characteristics (Frequency = 12.75 GHz to 13.25 GHz Unless Otherwise Stated; $T_c$ = 25 °C)

Characteristics	Symbol	Min.	Tvp.	Max.	Units	Conditions
DC Characteristics			- 71			
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-3.1	-2.9	-2.7	V	$V_{ps} = 10 \text{ V}, I_{p} = 27 \text{ mA}$
Gate Quiescent Voltage	V <sub>65(0)</sub>	-	-2.65	-	V <sub>DC</sub>	V <sub>pp</sub> = 40 V, I <sub>pp</sub> = 750 mA
Saturated Drain Current <sup>1</sup>	I <sub>DS</sub>	25.8	26.2	-	A	$V_{\rm DS} = 6.0 \text{ V}, V_{\rm GS} = 2.0 \text{ V}$
Drain-Source Breakdown Voltage	V <sub>BD</sub>	120	-	-	v	$V_{gs} = -8 \text{ V}, I_p = 27 \text{ mA}$
RF Characteristics <sup>2</sup>						
Small Signal Gain	S21 <sub>1</sub>	-	25	-	dB	P <sub>IN</sub> = -15 dBm, Freq = 12.75 - 13.25 GHz
Output Power	P <sub>OUT1</sub>	-	49.7	-	dBm	$V_{_{DD}}$ = 40 V, I $_{_{DQ}}$ = 750 mA, P $_{_{IN}}$ = 33 dBm, Freq = 12.75 GHz
Output Power	P <sub>OUT2</sub>	-	49.9	-	dBm	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 750 mA, $P_{_{IN}}$ = 33 dBm, Freq = 13.0 GHz
Output Power	P <sub>out3</sub>	-	49.7	-	dBm	V <sub>DD</sub> = 40 V, I <sub>DO</sub> = 750 mA, P <sub>IN</sub> = 33 dBm, Freq = 13.25 GHz
Power Added Efficiency	PAE <sub>1</sub>	-	23	-	%	$V_{_{DD}}$ = 40 V, $I_{_{DO}}$ = 750 mA, $P_{_{IN}}$ = 33 dBm, Freq = 12.75 GHz
Power Added Efficiency	PAE <sub>2</sub>	-	23	-	%	$V_{DD} = 40 \text{ V}, \text{ I}_{DQ} = 750 \text{ mA}, \text{ P}_{IN} = 33 \text{ dBm}, \text{ Freq} = 13.0 \text{ GHz}$
Power Added Efficiency	PAE <sub>3</sub>	-	21	-	%	$V_{_{DD}}$ = 40 V, I $_{_{DQ}}$ = 750 mA, P $_{_{IN}}$ = 33 dBm, Freq = 13.25 GHz
Power Gain	G <sub>p1</sub>	-	16.7	-	dB	V <sub>DD</sub> = 40 V, I <sub>DQ</sub> = 750 mA, P <sub>IN</sub> = 33 dBm, Freq = 12.75 GHz
Power Gain	G <sub>P2</sub>	-	16.9	-	dB	$V_{DD}$ = 40 V, $I_{DQ}$ = 750 mA, $P_{IN}$ = 33 dBm, Freq = 13.0 GHz
Power Gain	G <sub>P3</sub>	-	16.7	-	dB	$V_{_{DD}}$ = 40 V, I $_{_{DQ}}$ = 750 mA, P $_{_{\rm IN}}$ = 33 dBm, Freq = 13.25 GHz
Input Return Loss	S11	-	-18.6	-	dB	P <sub>IN</sub> = -15 dBm, 12.75 - 13.25 GHz
Output Return Loss	S22	-	-15.8	-	dB	P <sub>IN</sub> = -15 dBm, 12.75 - 13.25 GHz
IM3	IM3	-	-27	-	dBc	P <sub>out</sub> /Tone = 40 dBm, 10 MHz Spacing
Output Mismatch Stress	VSWR	-	-	3:1	Ψ	No Damage at All Phase Angles

Notes:

<sup>1</sup>Scaled from PCM data.

 $^2$  Unless otherwise noted:  $\mathsf{P}_{_{\rm IN}}$  = 33 dBm,  $\mathsf{V}_{_{\rm DD}}$  = 40 V,  $\mathsf{I}_{_{\rm DQ}}$  = 750 mA, CW.

## **Thermal Characteristics**

Parameter	Symbol	Rating	Units	Conditions
Operating Junction Temperature	T,	217	°C	
Thermal Resistance, Junction to Case	R <sub>ejc</sub>	0.56	°C/W	$CW, P_{\text{DISS}} = 230 \text{ W}, T_{\text{CASE}} = 85 \text{ C}$

<sup>2</sup> 

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Test conditions unless otherwise noted: V<sub>D</sub> = 40 V, I<sub>DQ</sub> = 750 mA, CW, P<sub>IN</sub> = 33 dBm, T<sub>BASE</sub> = +25 °C





Test conditions unless otherwise noted:  $V_{D} = 40 \text{ V}$ ,  $I_{DQ} = 750 \text{ mA}$ , CW,  $P_{IN} = 33 \text{ dBm}$ ,  $T_{BASE} = +25 \text{ °C}$ 





Test conditions unless otherwise noted:  $V_{D}$  = 40 V,  $I_{DO}$  = 750 mA, CW,  $P_{IN}$  = 33 dBm,  $T_{BASE}$  = +25 °C





Test conditions unless otherwise noted:  $V_{D}$  = 40 V,  $I_{DQ}$  = 750 mA, CW,  $P_{IN}$  = 33 dBm,  $T_{BASE}$  = +25 °C



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## Typical Performance of the CMPA1C1D080F

Test conditions unless otherwise noted:  $V_{D}$  = 40 V,  $I_{DQ}$  = 750 mA, CW,  $P_{IN}$  = 33 dBm,  $T_{BASE}$  = +25 °C





Figure 27. Gate Current vs Input Power as a Function of I<sub>DO</sub>

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Test conditions unless otherwise noted:  $V_{D}$  = 40 V,  $I_{DO}$  = 750 mA,  $P_{IN}$  = -15 dBm,  $T_{BASE}$  = +25 °C



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Test conditions unless otherwise noted:  $V_{D}$  = 40 V,  $I_{DO}$  = 750 mA,  $P_{IN}$  = -15 dBm,  $T_{BASE}$  = +25 °C



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## Typical Performance of the CMPA1C1D080F

Test conditions unless otherwise noted:  $V_D = 40 V$ ,  $I_{DO} = 750 mA$ , CW,  $P_{IN} = 33 dBm$ , Tone spacing = 10 MHz,  $T_{BASE} = +25 °C$ 





## Typical Performance of the CMPA1C1D080F

Test conditions unless otherwise noted: V<sub>D</sub> = 40 V, I<sub>DO</sub> = 750 mA, CW, P<sub>IN</sub> = 33 dBm, Tone spacing = 10 MHz, T<sub>BASE</sub> = +25 °C





## Typical Performance of the CMPA1C1D080F

Test conditions unless otherwise noted:  $V_D = 40 V$ ,  $I_{DO} = 750 mA$ , CW,  $P_{IN} = 33 dBm$ , Tone spacing = 10 MHz,  $T_{BASE} = +25 °C$ 







Test conditions unless otherwise noted:  $V_D = 40 V$ ,  $I_{DQ} = 750 mA$ , CW,  $P_{IN} = 33 dBm$ , Tone spacing = 10 MHz,  $T_{BASE} = +25 °C$ 



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## CMPA1C1D080F-AMP Evaluation Board Schematic



## CMPA1C1D080F-AMP Evaluation Board Outline



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## CMPA1C1D080F-AMP Evaluation Board Bill of Materials

Designator	Description	Qty
C1, C3	CAP, 33000 PF, 0805, 100 V, X7R	2
C2, C4, C6, C9	CAP, 2.2 UF, 100 V, 10%, X7R, 1210	4
C7, C10	CAP, 10 UF, 100 V, 10%, X7R, 2220	2
C11	CAP, 100 UF, 20%, 160 V, ELEC	1
W1	WIRE, 18 AWG ~ 3"	1
W2, W3	WIRE, 18 AWG ~ 1.75"	2
J1, J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20 MIL	2
J3, J4	HEADER RT>PLZ .1CEN LK 9POS	2
J5	CONN, SMB, STRAIGHT JACK RECEPTACLE, SMT, 50 OHM, Au PLATED	1
	PCB, TEST FIXTURE, 440222 PKG	1
	BASEPLATE, CU, 2.5 X 4.0 X 0.5 IN	1
	2-56 SOC HD SCREW 1/4 SS	4
	#2 SPLIT LOCKWASHER SS	4
Q1	MMIC CMPA1C1D080F	1

## **Electrostatic Discharge (ESD) Classifications**

Parameter	Symbol	Class	Test Methodology
Human Body Model	НВМ	1 B (≥ 500 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	II (≥ 200 V)	JEDEC JESD22 C101-C



## Product Dimensions CMPA1C1D080F (Package 440222)

NOTES:

1. DIMENSIONING AND TOLERANICING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.

4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008' IN ANY DIRECTION.

5. ALL PLATED SURFACES ARE NI/AU

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
A	0.679	0.691	17.25	17.55
В	0.003	0.006	0.076	0.152
С	0.214	0.241	5.44	6.12
D	0.307	0.323	7.80	8.20
E	0.016	0.032	0.406	0.813
F	0.047	0.063	1.194	1.600
G	0.936	0.954	23.77	24.23
н	0.912	0.930	23.16	23.62
J	0.795	0.811	20.19	20.60
к	ø0.094	ø0.110	ø2.39	ø2.79
L	0.062	0.078	1.575	1.981
М	0.006	0.022	0.152	0.559
N	0.004	0.018	0.102	0.457







	-
Pin	Desc.
1	Bias Gate 2
2	Bias Gate 2
3	GND
4	RF_IN
5	GND
6	Bias Gate 1
7	Bias Gate 1
8	Bias Drain 2
9	Bias Drain 2
10	GND
11	RF_OUT
12	GND
13	Bias Drain 1
14	Bias Drain 1
	· · · · · · · · · · · · · · · · · · ·



#### **Part Number System**



#### Table 1.

Parameter	Value	Units
Lower Frequency	12.75	GHz
Upper Frequency	13.25	GHz
Power Output	80	W
Package	Flange	-

Note:

Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

#### Table 2.

Code Value
0
1
2
3
4
5
6
7
8
9
1 A = 10.0 GHz 2 H = 27.0 GHz



## **Product Ordering Information**

Order Number	Description	Unit of Measure	Image
CMPA1C1D080F	GaN HEMT	Each	CHARLESSON
CMPA1C1D080F-AMP	Test Board with GaN MMIC Installed	Each	

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